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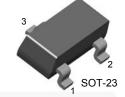
December 2013



MMBT3646 NPN Switching Transistor

Features

- NPN High Speed Switching Transistor
- Process 22



1. Base 2. Emitter 3. Collector

Ordering Information

Part Number	Top Mark	Package	Packing Method
MMBT3646	23	SOT-23 3L	Tape and Reel

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_c = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	15	V
V _{CES}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5	V
۱ _C	Collector Current (DC) - Continuous	300	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°C

Thermal Characteristics⁽¹⁾

Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P _D	Total Device Dissipation at T _A = 25°C	625	mW
	Derate Above 25°C	5	mW/°C
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient 200		°C/W

Note:

1. PCB size: FR-4 trace width is 50 mil / 25 mil /15 mil, thickness: 2 OZ, minimum land pattern size.

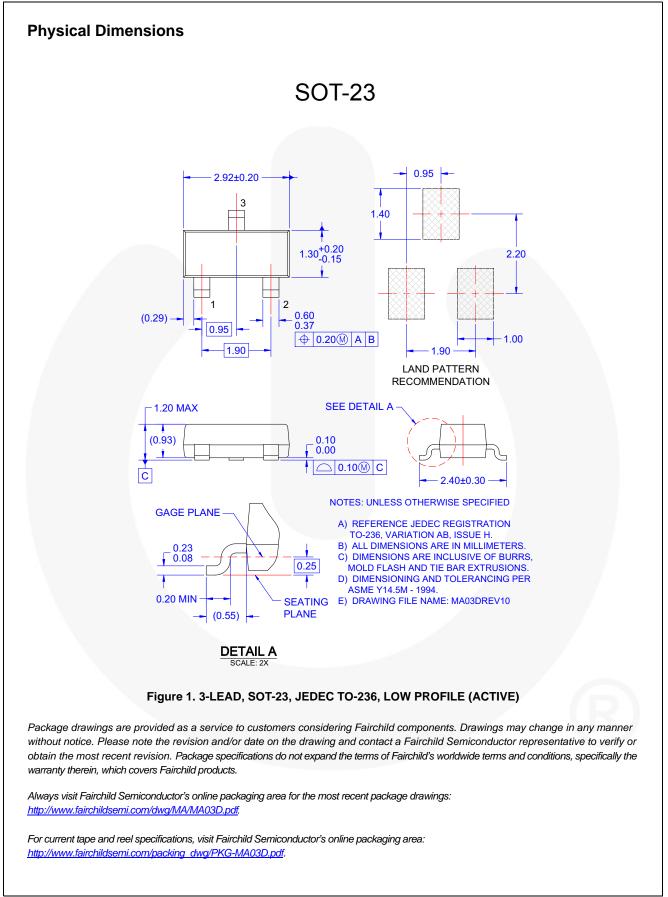
Electrical Characteristics

Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	I _C = 100 μA, V _{BE} = 0	40			V
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage ⁽²⁾	I _C = 10 mA, I _B = 0	15			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 100 μA, I _E = 0	40			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 100 \ \mu A, I_{C} = 0$	5			V
	Collector Cut-Off Current	V_{CE} = 20 V, V_{BE} = 0			0.5	
I _{CES}		$V_{CE} = 20 \text{ V}, \text{ V}_{BE} = 0,$ $T_A = 65^{\circ}\text{C}$			3.0	μA
		V _{CE} = 0.4 V, I _C = 30 mA	30		120	
h _{FE}	DC Current Gain ⁽²⁾	V_{CE} = 0.5 V, I _C = 100 mA	25			
		V _{CE} = 1.0 V, I _C = 300 mA	15			
V _{CE} (sat)	Collector-Emitter Saturation Voltage ⁽²⁾	I _C = 30 mA, I _B = 3 mA			0.20	
		I _C = 100 mA, I _B = 10 mA			0.28	V
		I _C = 300 mA, I _B = 30 mA			0.50	
		$I_{C} = 30 \text{ mA}, I_{B} = 3 \text{ mA}, T_{A} = 65^{\circ}\text{C}$			0.30	
	Base-Emitter Saturation Voltage ⁽²⁾	I _C = 30 mA, I _B = 3 mA	0.73		0.95	v
V _{BE} (sat)		I _C = 100 mA, I _B = 10 mA			1.20	
		I _C = 300 mA, I _B = 30 mA			1.70	
C _{ob}	Output Capacitance	V _{CE} = 5 V, I _E = 0, f = 1MHz			5	pF
C _{ib}	Input Capacitance	V _{EB} = 0.5 V, I _C = 0, f = 1MHz			8	pF
t _{on}	Turn-On Time	V _{CC} = 10 V, I _C = 300 mA,			18	ns
t _d	Delay Time	I _{B1} = 30 mA,			10	ns
t _r	Rise Time	$V_{CE}(off) = 3 V$			15	ns
t _{off}	Turn-Off Time				28	ns
t _f	Fall Time	$V_{CC} = 10 \text{ V}, I_C = 300 \text{ mA},$ $I_{B1} = I_{B2} = 30 \text{ mA}$			15	ns
t _s	Storage Time				20	ns

Note:

2. Pulse test: pulse width \leq 300 µs, duty cycle \leq 2.0%.



MMBT3646

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• NPN Switching Transistor

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